

LT023WS

Features

- Wide temperature range
(-30°C to $+85^{\circ}\text{C}$)
 - Low noise
S/N: -80 dB (according to
measurement method Fig. 27-2)
 - Wavelength: 780nm
 - Single transverse mode
 - Multi longitudinal mode

Applications

- Video disc players
 - Fiber optic communications
 - Light source for analog processing
 - Measurement Instruments
 - Analysis Instruments



Absolute Maximum Ratings

Parameter	Symbol	Ratings	Units
Optical power output	P _o	5	mW
Reverse voltage	V _R	2	V
Laser PIN		30	
Operating temperature * ¹	T _{opr}	-30 to +85	°C
Storage temperature * ²	T _{sto}	-40 to +100	°C

* 1 Case temperature

Electro-optical Characteristics *

Parameter	Symbol	condition	Rating*	Units
			MIN TYP P	MAX
Threshold current	I _{th}	—	45	mA
Operating current	I _{op}	P _o =3mW	55	mA
Operating voltage	V _{op}	P _o =3mW	175	V
Wavelength* ²	λ _p	P _o =3mW	770	nm
Monitor current	I _m	P _o =3mW V _R =15V	008	mA
Radiation characteristics	Angle* ³	Parallel to junction	θ //	P _o =3mW
		Perpendicular to junction	θ ⊥	P _o =3mW
	Ripple	—	—	P _o =3mW
Emission point accuracy	Angle	—	Δφ //	P _o =3mW
		—	Δφ ⊥	P _o =3mW
	Position	Δx, Δy, Δz	—	—
Differential efficiency	η	2mW I _F (3mW) - I _F (1mW)	0.1	mW/mA
Coherence	γ	P _o =3mW	—	0.47

* 1 Initial value

* 3 Angle at 50% peak Intensity (full width at half-maximum)

Initial value

Electrical Characteristics of Photodiode

Parameter	Symbol	Condition	Ratings			Units
			MIN	TYP	MAX	
Sensitivity	S	$V_R = 15V$	—	0.07	—	mA/mW
Dark current	I_D	$V_R = 15V$	—	—	150	nA
Terminal capacitance	C_t	$V_R = 15V$	—	9	—	pF